# **SWITCHMODE**Schottky Power Rectifier

The SWITCHMODE Power Rectifier employs the Schottky Barrier principle in a large area metal-to-silicon power diode. State-of-the-artgeometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for use as rectifiers in very low-voltage, high-frequency switching power supplies, free wheeling diodes and polarity protection diodes.

#### **Features**

- Highly Stable Oxide Passivated Junction
- Very Low Forward Voltage Drop
- Matched Dual Die Construction
- High Junction Temperature Capability
- High dv/dt Capability
- Excellent Ability to Withstand Reverse Avalanche Energy Transients
- Guardring for Stress Protection
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Electrically Isolated. No Isolation Hardware Required.
- These are Pb-Free Devices

#### **Mechanical Characteristics:**

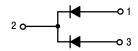
- Case: Epoxy, Molded
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds

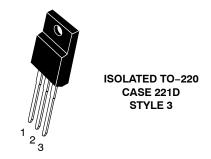


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## SCHOTTKY BARRIER RECTIFIER 20 AMPERES, 100 VOLTS





#### ORDERING AND MARKING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

#### MAXIMUM RATINGS (Per Leg)

Rating		Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	100	V
Average Rectified Forward Current (Rated V <sub>R</sub> ), T <sub>C</sub> = 133°C	Total Device	I <sub>F(AV)</sub>	10 20	Α
Peak Repetitive Forward Current (Rated V <sub>R</sub> , Square Wave, 20 kHz), T <sub>C</sub> = 133°C		I <sub>FRM</sub>	20	А
Non-repetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)		I <sub>FSM</sub>	150	Α
Peak Repetitive Reverse Surge Current (2.0 μs, 1.0 kHz)		I <sub>RRM</sub>	0.5	Α
Operating Junction and Storage Temperature Range (Note 1)		T <sub>J</sub> , T <sub>stg</sub>	– 65 to +175	°C
Voltage Rate of Change (Rated V <sub>R</sub> )		dv/dt	10000	V/μs
RMS Isolation Voltage (t = 0.3 second, R.H. $\leq$ 30%, T <sub>A</sub> = 25°C) (Note 2)		V <sub>iso1</sub>	4500	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

## THERMAL CHARACTERISTICS (Per Leg)

Rating	Symbol	Value	Unit
Maximum Thermal Resistance, Junction to Case	$R_{ heta JC}$	3.5	°C/W
Lead Temperature for Soldering Purposes: 1/8" from Case for 5 Seconds	T <sub>L</sub>	260	°C

#### **ELECTRICAL CHARACTERISTICS** (Per Leg)

Characteristic	Symbol	Max	Unit
Maximum Instantaneous Forward Voltage (Note 3)	VF		V
(i <sub>F</sub> = 10 Amp, T <sub>C</sub> = 25°C)	·	0.85	
(i <sub>F</sub> = 10 Amp, T <sub>C</sub> = 125°C)		0.75	
$(i_F = 20 \text{ Amp}, T_C = 25^{\circ}C)$		0.95	
(i <sub>F</sub> = 20 Amp, T <sub>C</sub> = 125°C)		0.85	
Maximum Instantaneous Reverse Current (Note 3)	i <sub>R</sub>		mA
(Rated DC Voltage, T <sub>C</sub> = 25°C)		0.15	
(Rated DC Voltage, T <sub>C</sub> = 125°C)		150	

- 1. The heat generated must be less than the thermal conductivity from Junction-to-Ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ .
- 2. Proper strike and creepage distance must be provided.
- 3. Pulse Test: Pulse Width = 300  $\mu$ s, Duty Cycle  $\leq$  2.0%.

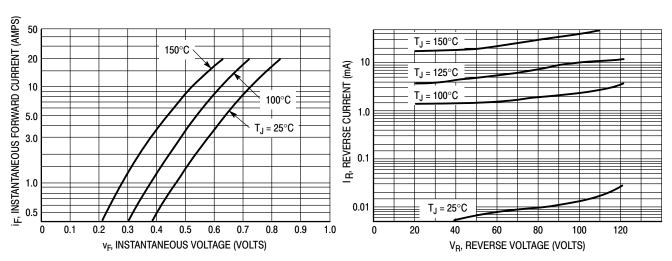
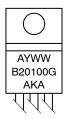


Figure 1. Typical Forward Voltage Per Diode

Figure 2. Typical Reverse Current Per Diode

#### **MARKING DIAGRAMS**



TO-220

B20100 = Device Code A = Assembly Location

Y = Year
WW = Work Week
G = Pb-Free Package
AKA = Polarity Designator

#### **ORDERING INFORMATION**

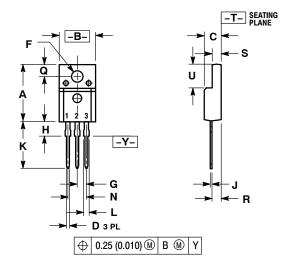
Device	Package	Shipping <sup>†</sup>
MBRF20100CTG	TO-220 (Pb-Free)	50 Units / Rail

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### PACKAGE DIMENSIONS

#### TO-220 FULLPAK CASE 221D-03

ISSUE K



#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH 3. 221D-01 THRU 221D-02 OBSOLETE, NEW STANDARD 221D-03.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.617	0.635	15.67	16.12
В	0.392	0.419	9.96	10.63
С	0.177	0.193	4.50	4.90
D	0.024	0.039	0.60	1.00
F	0.116	0.129	2.95	3.28
G	0.100 BSC		2.54 BSC	
Н	0.118	0.135	3.00	3.43
J	0.018	0.025	0.45	0.63
K	0.503	0.541	12.78	13.73
L	0.048	0.058	1.23	1.47
N	0.200 BSC		5.08 BSC	
Q	0.122	0.138	3.10	3.50
R	0.099	0.117	2.51	2.96
S	0.092	0.113	2.34	2.87
U	0.239	0.271	6.06	6.88

#### STYLE 3:

PIN 1. ANODE

- CATHODE 2.
- ANODE

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